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Kind regards,

Team Nexperia



PIMZ2; PUMZ2 NPN/PNP general-purpose double transistors Rev. 06 — 17 November 2009

Product data sheet

Product profile

1.1 General description

NPN/PNP general-purpose double transistors.

Table 1. **Product overview**

Type number	Package		Configuration
	NXP	JEITA	
PIMZ2	SOT457	SC-74	NPN/PNP double transistors
PUMZ2	SOT363	SC-88	NPN/PNP double transistors

1.2 Features

- Simplified circuit design
- Reduced component count
- Reduced pick and place costs

1.3 Applications

General-purpose switching and amplification

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	50	V
Ic	collector current (DC)		-	-	150	mA



sym083

NPN/PNP general-purpose double transistors

2. **Pinning information**

Table 3.	Pinning				
Pin	Description	Simplified outline	Symbol		
PIMZ2 (So	OT457)				
1	collector TR2	D. D. D.			
2	emitter TR2	<u> </u>	6 5 4		
3	collector TR1		لم		
4	emitter TR1	1 1 2 3	TR1		
5	base TR1		TR2		
6	base TR2		1 1 1 1 2 3 sym082		
PUMZ2 (S	OT363)				
1	emitter TR1	D. D. D.			
2	base TR1	[6 [5]4	6 5 4		
3	base TR2		TR2		
4	collector TR2	0	TR1		
5	emitter TR2	□1 □2 □3			
6	collector TR1		1 2 3		

Ordering information 3.

Table 4. **Ordering information**

Type number	Package	Package				
	Name	Description	Version			
PIMZ2	SC-74	plastic surface mounted package; 6 leads	SOT457			
PUMZ2	SC-88	plastic surface mounted package; 6 leads	SOT363			

Marking 4.

Table 5. **Marking codes**

Type number	Marking code ^[1]
PIMZ2	M6
PUMZ2	GZ*

[1] * = -: made in Hong Kong

* = t: made in Malaysia

* = W: made in China

5. **Limiting values**

Table 6. **Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
Per transis	stor; for the PNP transistor	with negative pola	rity		
V_{CBO}	collector-base voltage	open emitter	-	60	V
V_{CEO}	collector-emitter voltage	open base	-	50	V
V_{EBO}	emitter-base voltage	open collector	-	7	V
I _C	collector current (DC)		-	150	mA
I _{CM}	peak collector current		-	200	mA
I _{BM}	peak base current		-	100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$			
	SOT457		<u>[1]</u> -	200	mW
	SOT363		<u>[1]</u> -	180	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
Per device)				
P _{tot}	total power dissipation	$T_{amb} \leq 25 ^{\circ}C$			
	SOT457		<u>[1]</u> -	300	mW
	SOT363		[1] -	300	mW

^[1] Device mounted on an FR4 printed-circuit board.

Thermal characteristics

Thermal characteristics Table 7.

Parameter	Conditions	Min	Тур	Max	Unit
sistor					
thermal resistance from junction to ambient	$T_{amb} \le 25 ^{\circ}C$				
SOT457		[1] -	-	625	K/W
SOT363		[1] -	-	694	K/W
ce					
thermal resistance from junction to ambient	$T_{amb} \le 25 ^{\circ}C$				
SOT457		[1] -	-	417	K/W
SOT363		<u>[1]</u> -	-	417	K/W
	thermal resistance from junction to ambient SOT457 SOT363 ce thermal resistance from junction to ambient SOT457	thermal resistance from junction to ambient $T_{amb} \le 25 ^{\circ}\text{C}$ SOT457 SOT363 Telephone $T_{amb} \le 25 ^{\circ}\text{C}$ To junction to ambient $T_{amb} \le 25 ^{\circ}\text{C}$ To junction to ambient $T_{amb} \le 25 ^{\circ}\text{C}$	thermal resistance from junction to ambient	thermal resistance from junction to ambient	thermal resistance from junction to ambient

^[1] Device mounted on an FR4 printed-circuit board.

Product data sheet

7. Characteristics

Table 8. Characteristics

 $T_{amb} = 25$ °C unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Symbol	Parameter	Conditions	141111	Тур	IVIAX	Onit
Per trans	sistor; for the PNP transistor	with negative polarity; unless otherwise	e specified			
I_{CBO}	collector-base cut-off current	$V_{CB} = 60 \text{ V}; I_E = 0 \text{ A}$	-	-	100	nA
		$V_{CB} = 60 \text{ V}; I_E = 0 \text{ A}; T_j = 150 ^{\circ}\text{C}$	-	-	50	μΑ
I_{EBO}	emitter-base cut-off current	$V_{EB} = 7 \text{ V}; I_{C} = 0 \text{ A}$	-	-	100	nA
h _{FE}	DC current gain	V _{CE} = 6 V; I _C = 1 mA	120	250	560	
TR1 (PN	P)					
V_{CEsat}	collector-emitter saturation voltage	$I_C = -50 \text{ mA}; I_B = -5 \text{ mA}$	-	-	-500	mV
f _T	transition frequency	$I_E = -2 \text{ mA}; V_{CE} = -12 \text{ V}; f = 100 \text{ MHz}$	-	190	-	MHz
C _c	collector capacitance	$I_E = i_e = 0 \text{ A}; V_{CB} = -12 \text{ V}; f = 1 \text{ MHz}$	-	2.3	5	pF
TR2 (NP	N)					
V _{CEsat}	collector-emitter saturation voltage	$I_C = 50 \text{ mA}; I_B = 5 \text{ mA}$	-	-	250	mV
f _T	transition frequency	$I_E = 2 \text{ mA}; V_{CE} = 12 \text{ V}; f = 100 \text{ MHz}$	100	-	-	MHz
C _c	collector capacitance	$I_E = i_e = 0 \text{ A}; V_{CB} = 12 \text{ V}; f = 1 \text{ MHz}$	-	-	3	pF

8. Package outline

Plastic surface-mounted package (TSOP6); 6 leads

SOT457

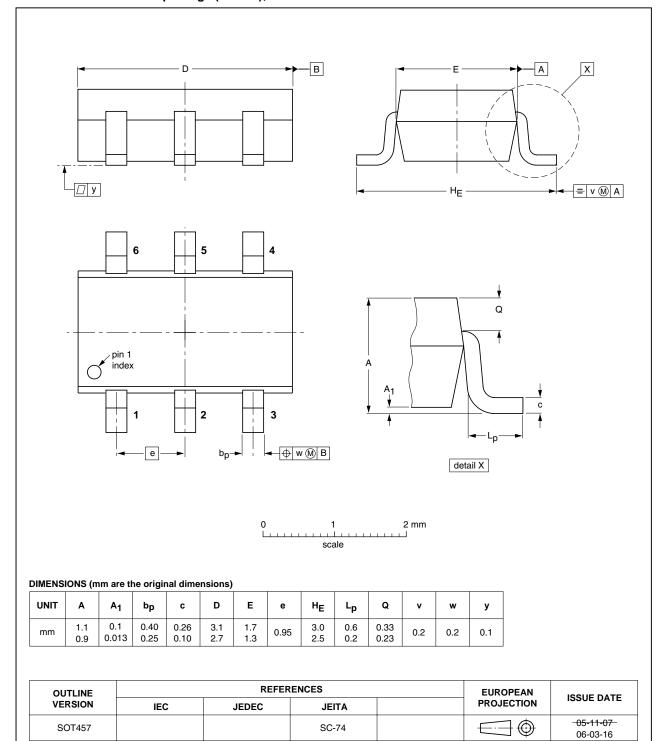


Fig 1. Package outline SOT457 (SC-74)

PIMZ2_PUMZ2_6

Plastic surface-mounted package; 6 leads **SOT363** В X = v M A ⊕ w M B detail X 2 mm **DIMENSIONS (mm are the original dimensions)** UNIT D С Ε е ΗE Lp Q у max 0.30 0.25 2.2 1.35 0.45 0.25 1.1 2.2 0.1 0.65 mm 0.2 0.2 0.1 0.20 8.0 0.10 1.15 1.8 0.15 0.15 REFERENCES EUROPEAN PROJECTION OUTLINE ISSUE DATE VERSION IEC **JEDEC JEITA** 04-11-08 \bigcirc SOT363 SC-88 06-03-16

Fig 2. Package outline SOT363 (SC-88)

PIMZ2_PUMZ2_6

9. Revision history

Table 9. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
PIMZ2_PUMZ2_6	20091117	Product data sheet	-	PIMZ2_PUMZ2_5		
Modifications:	 This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content. 					
	 Table 3 "Pinr 	ning": updated				
	Figure 1 "Page	ckage outline SOT457 (SC-7	<u>'4)"</u> : updated			
	 Figure 2 "Page 	ckage outline SOT363 (SC-8	88)": updated			
PIMZ2_PUMZ2_5	20041124	Product data sheet	-	PIMZ2_PUMZ2_4		
PIMZ2_PUMZ2_4	20031217	Product specification	-	PIMZ2_2		
PIMZ2_2	20030714	Product specification	-	PIMZ2_1		
PIMZ2_1	20030602	Objective specification	-	-		

10. Legal information

10.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- The term 'short data sheet' is explained in section "Definitions".
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Product data sheet

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